


Erratum: Heavy-hole–light-hole exciton system in GaAs/AlGaAs quantum wells
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Table III in the Appendix of our paper should be replaced by the corrected table below. The remaining results of the paper are unaffected by these corrections.

TABLE III. Fitting parameters of Eq. (A5) for aluminum concentration in the barriers $x = 0.3$.

Type	a	b	c	d	L_{low} (nm)	SD (μeV)
X_{hh1}	29592	2.5369	43.46	−4.06	10	18
X_{hh2}	25563	2.3016	22.70	−3.88	10	52
X_{hh3}	14014	2.0000	4.4546	−4.02	30	24
X_{hh4}	50038	2.1437	38.04	−4.06	50	37
X_{lh1}	45868	2.5310	54.32	−4.01	10	13
X_{lh2}	93427	2.3966	56.75	−3.98	14	20
X_{lh3}	77334	2.2000	12.564	−4.00	60	41